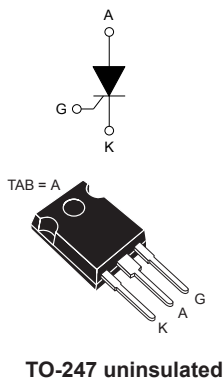


80 A 800 V high temperature thyristor (SCR) in TO-247 package



Features

- High junction temperature: $T_j = 150\text{ °C}$
- Blocking voltage: $V_{DRM} = V_{RRM} = 800\text{ V}$
- Nominal current: $I_{T(RMS)} = 80\text{ A}$
- Gate triggering current: $I_{GT\text{ max.}} = 50\text{ mA}$
- High noise immunity: $dV/dt > 1\text{ kV}/\mu\text{s}$
- Through hole package TO-247
- Increase of thermal margin due to extended T_j up to 150 °C
- Low I_D and I_R in blocking state
- [Ecopack2](#) (includes halogen free & RoHS compliance)

Applications

- AC-DC rectifier controlled bridge
- Variable speed motor drive
- Battery charging system
- AC solid state relay
- By pass switch of UPS
- Industrial welding systems
- Motor soft starter systems

Product status link

[TM8050H-8W](#)

Product summary

$I_{T(RMS)}$	80 A
V_{DRM}/V_{RRM}	800 V
I_{GT}	50 mA
T_j	150 °C

Description

Available in through hole package TO-247, the [TM8050H-8W](#) is an 800 V SCR thyristor suitable for applications where high power switching ($I_{T(RMS)} = 80\text{ A}$) and low power dissipation ($V_{TM} = 1.55\text{ V}$ at 160 A) are key features. These features make it ideal for motorbike voltage regulator, by-pass AC switch, controlled rectifier bridge, solid state relay, battery charger, welding equipment and motor driver applications.

1 Characteristics

Table 1. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (180 ° conduction angle)		$T_C = 126\text{ °C}$	80	A
$I_{T(AV)}$	Average on-state current (180 ° conduction angle)			50	A
I_{TSM}	Non repetitive surge peak on-state current, $V_R = 0\text{ V}$	$t_p = 8.3\text{ ms}$	$T_j\text{ initial} = 25\text{ °C}$	731	A
		$t_p = 10\text{ ms}$		670	
I^2t	I^2t value for fusing		$T_j = 25\text{ °C}$	2245	A ² s
V_{RRM} / V_{DRM}	Maximum repetitive symmetric blocking voltage			800	V
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	$f = 50\text{ Hz}$	$T_j = 25\text{ °C}$	200	A/ μ s
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu$ s	$T_j = 150\text{ °C}$	8	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ °C}$	1	W
V_{RGM}	Maximum peak reverse gate voltage			5	V
T_{stg}	Storage junction temperature range			-40 to +150	°C
T_j	Maximum operating junction temperature			-40 to +150	°C

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$ unless otherwise specified)

Symbol	Test Conditions		Value	Unit	
I_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$	Min.	2.5	mA	
		Max.	50		
V_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$	Max.	1.5	V	
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	$T_j = 150\text{ °C}$	Min.	0.2	V
I_H	$I_T = 500\text{ mA}$, gate open		Max.	100	mA
I_L	$I_G = 1.2 \times I_{GT}$		Max.	125	mA
t_{gt}	$I_T = 80\text{ A}$, $V_D = V_{DRM}$, $I_G = 200\text{ mA}$, $di_G/dt = 0.2\text{ A}/\mu$ s		Typ.	3	μ s
dV/dt	$V_D = 67\%$ V_{DRM} , gate open	$T_j = 150\text{ °C}$	Min.	1000	V/ μ s
t_q	$I_T = 33\text{ A}$, $di_T/dt = 10\text{ A}/\mu$ s, $V_R = 75\text{ V}$, $V_D = 400\text{ V}$, $dV_D/dt = 20\text{ V}/\mu$ s, $t_p = 100\text{ }\mu$ s	$T_j = 150\text{ °C}$	Max.	150	μ s

Table 3. Static characteristics

Symbol	Test conditions		Value	Unit	
V_{TM}	$I_{TM} = 160\text{ A}$, $t_p = 380\text{ }\mu$ s	$T_j = 25\text{ °C}$	Max.	1.55	V
V_{TO}	On state threshold voltage		Max.	0.85	
R_D	On state dynamic resistance		Max.	5.5	m Ω
I_{DRM}	$V_D = V_{DRM} = V_R = V_{RRM} = 800\text{ V}$	$T_j = 25\text{ °C}$	Max.	20	μ A
I_{RRM}		$T_j = 150\text{ °C}$	Max.	2.5	mA

Table 4. Thermal parameters

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (DC,max.)	0.30	°C/W
$R_{th(j-a)}$	Junction to ambient DC (typ.)	50	

1.1 Characteristics curves

Figure 1. Maximum average power dissipation versus average on-state current

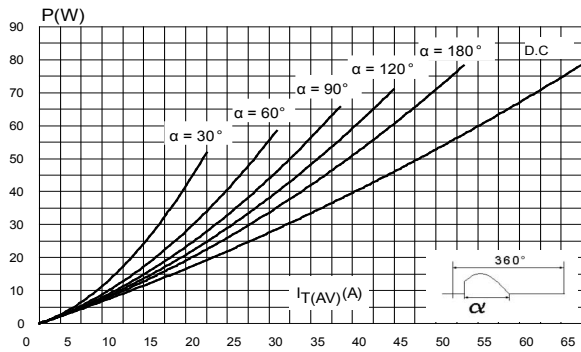


Figure 2. Average and DC on-state current versus case temperature

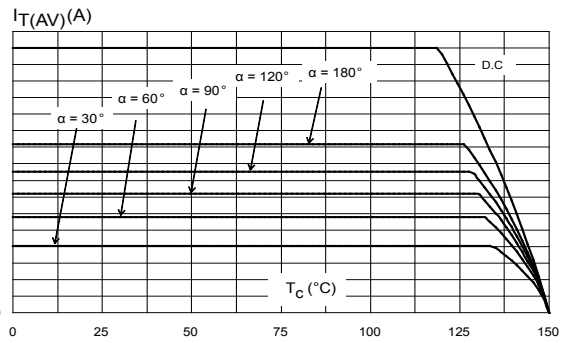


Figure 3. Average and D.C. on state current versus ambient temperature

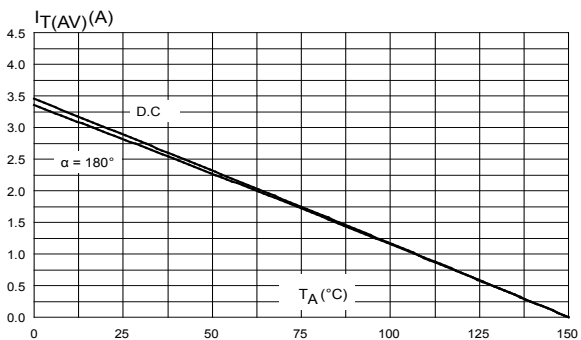


Figure 4. On-state characteristics (maximum values)

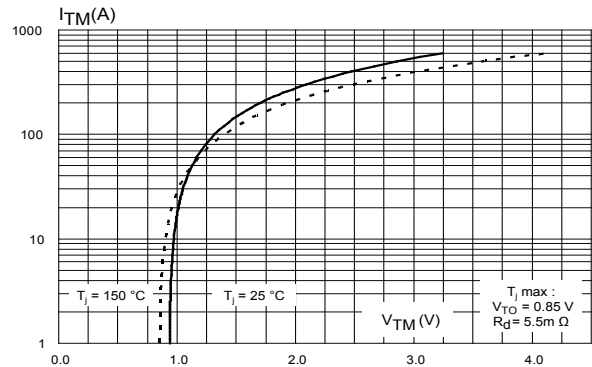


Figure 5. Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration

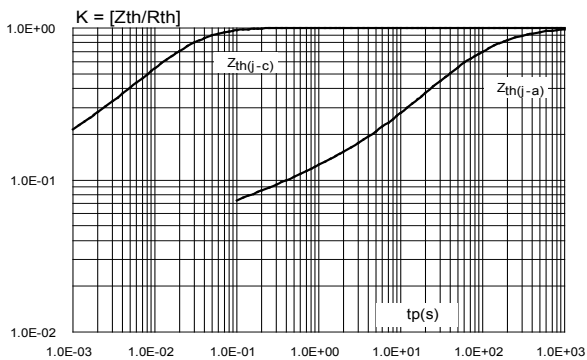


Figure 6. Relative variation of gate trigger current and gate voltage versus junction temperature

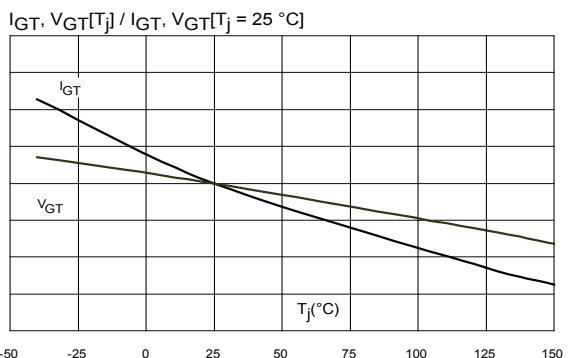


Figure 7. Relative variation of holding current and latching current versus junction temperature (typical values)

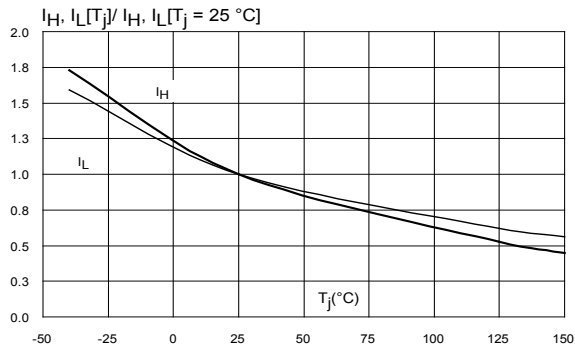


Figure 8. Surge peak on state current versus number of cycles

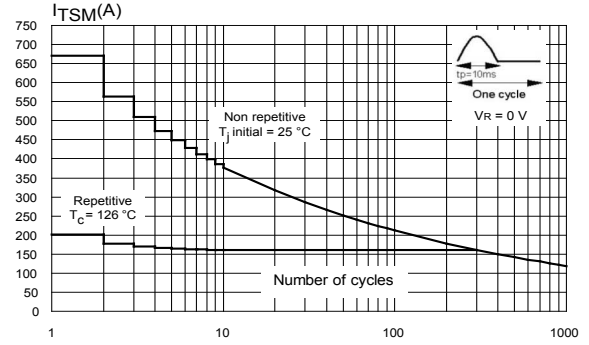


Figure 9. Non repetitive surge peak on state current for a half cycle sine pulse versus pulse width $t_p < 10\text{ ms}$

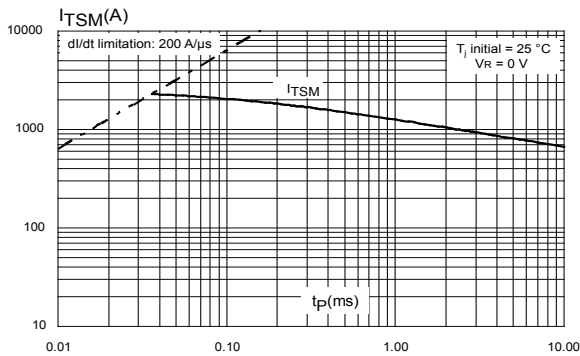


Figure 10. Relative variation of leakage current versus junction temperature for different values of blocking voltage

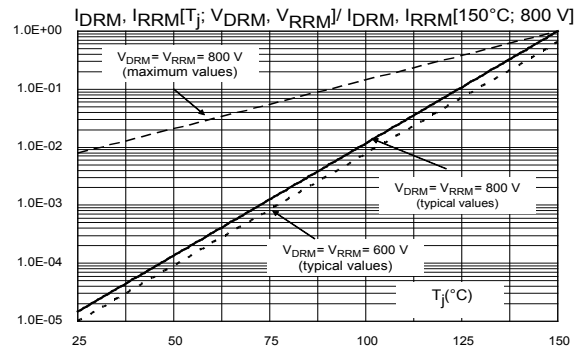
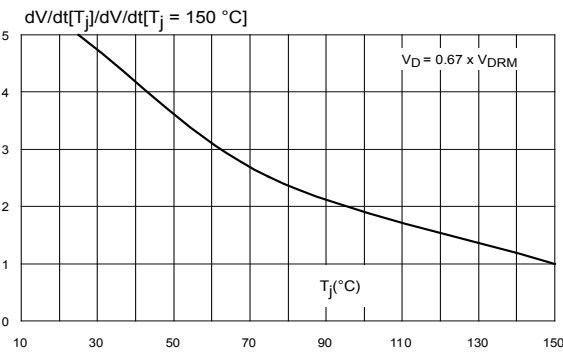


Figure 11. Relative variation of static dV/dt immunity versus junction temperature (typical values)



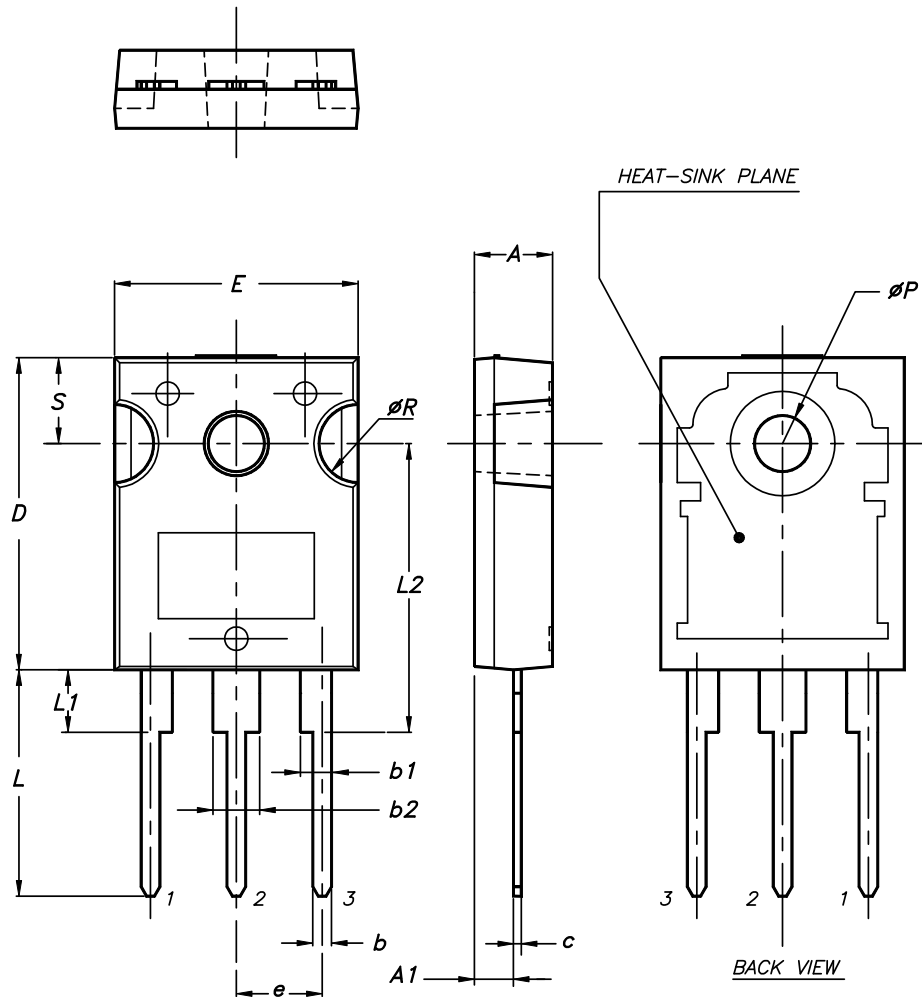
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-247 package information

- Epoxy meets UL 94,V0
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1 N·m

Figure 12. TO-247 package outline



0075325_9

Table 5. TO-247 package mechanical data

Dim.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.85		5.15	0.1909		0.2028
A1	2.20		2.60	0.0866		0.1024
b	1.0		1.40	0.0394		0.0551
b1	2.0		2.40	0.0787		0.0945
b2	3.0		3.40	0.1181		0.1339
c	0.40		0.80	0.0157		0.0315
D ⁽²⁾	19.85		20.15	0.7815		0.7933
E	15.45		15.75	0.6083		0.6201
e	5.30	5.45	5.60	0.2087	0.2146	0.2205
L	14.20		14.80	0.5591		0.5827
L1	3.70		4.30	0.1457		0.1693
L2		18.50			0.7283	
ØP ⁽³⁾	3.55		3.65	0.1398		0.1437
ØR	4.50		5.50	0.1772		0.2165
S	5.30	5.50	5.70	0.2087	0.2165	0.2244

1. Inch dimensions given only for reference
2. Dimension D plus gate protrusion does not exceed 20.5 mm
3. Resin thickness around the mounting hole is not less than 0.9 mm

3 Ordering information

Figure 13. Ordering information scheme

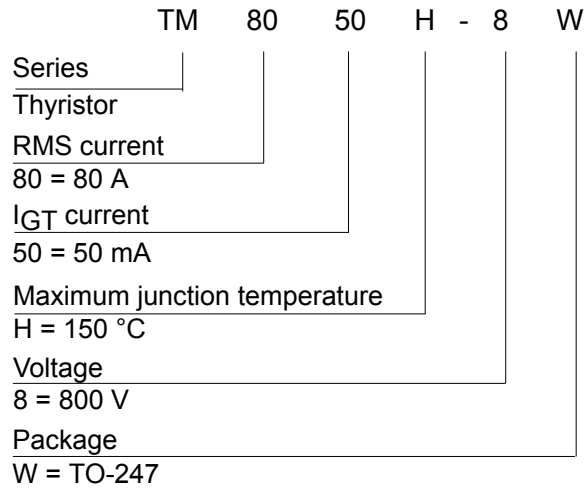


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TM8050H-8W	TM8050H8	TO-247	4.43 g	30	Tube

Revision history

Table 7. Document revision history

Date	Revision	Changes
03-May-2016	1	Initial release.
08-Aug-2019	2	Updated Table 1 , Figure 8 and Figure 9 . Minor text change.

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